

I GBT

# Insulated Gate Bipolar Transistor

I GBT MOSFET GTR

I GBT

5KHz 40KHz 40KHz 150KHz

I GBT

I GBT

I GBT

I GBT

1

I GBT

I GBT

2

I GBT

Vces

Vces

I GBT

FRED

I GBT Vce(sat)

+VG=14 15V -VG=5 10V

Rg I GBT

Rg

Rg

( )

Rg

5

100

20K 30K

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, 表面平整度

35um 同时表面粗糙度小于15um

1/3

I GBT

1/3

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